Supporting Information for

Two-dimensional transitional metal dihydrides crystals with anisotropic and spin-polarized Fermi Dirac cone

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Figure S1. The structural snapshots of Born-Oppenheimer Molecular Dynamic simulations for (a) T-MoH₂, (b) H-MoH₂, (c) WH₂ (up and down = T and H) nanosheets, respectively.



Figure S2. The phonon dispersion spectra of 2D (a)T-WH₂ and (b)H-WH₂.



Figure S3. The partial DOS projected on atomic orbitals of 2D (a) T-MoH₂, (b) T-WH₂, band structure of (c) H-MoH₂, (d) T-WH₂ and (e) H-WH₂. The fermi level is set as 0 eV.

Table S1. The energy difference between unit-cell of T-MH₂ and H-MH₂ in ground state in eV per unit cell.

system	T-MoH ₂	H-MoH ₂	T-WH ₂	H-WH ₂
ΔΕ	0.000	0.455	0.000	0.364

Table S2. The calculated metal-hydrogen (M-H) bond strength of 2D MH₂ in eV per M-H bond.

system	T-MoH ₂	H-MoH ₂	T-WH ₂	H-WH ₂
E _{BS}	1.800	1.691	1.600	1.521

Table S3. The energy difference between FM, NM and AFM states of unit-cell of 2D MH₂ monolayers in ground state in eV per metal atom.

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syste	em	E _{FM}	E _{AFM}	E _{NM}
MoH ₂	Т	0.000	0.038	0.248
	Н	/	/	/
WH ₂	Т	0.000	0.114	0.201
	Н	0.110	0.000	0.247